

Printed Pages: 02

Paper Id: 131406

Sub Code: EEC401

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BTECH
(SEM IV) THEORY EXAMINATION 2017-18
ELECTRONIC CIRCUITS

Time: 3 Hours**Total Marks: 100****Note: 1.** Attempt all Sections. If require any missing data; then choose suitably.**SECTION A****1. Attempt all questions in brief. 2 x 10 = 20**

- a) Define Power Supply Rejection Ratio (PSRR)?
- b) What are the characteristics of an Ideal op-amps?
- c) What is meant by drain-source saturation current?
- d) How is threshold voltage of the MOSFET adjusted?
- e) What is the significance of transistor biasing?
- f) Define the Beta of a transistor? expression
- g) Write the expression for voltage gain with negative and positive feedback?
- h) What is the Barkhausen criterion for oscillation?
- i) What are the basic topology of feedback?
- j) Draw the small signal model of BJT?

SECTION B**2. Attempt any three of the following: 10 x 3 = 30**

- a) Explain the working of an op-amp inverting amplifier? Derive the expression for its voltage gain?
- b) Draw and Explain the transfer characteristic of a MOSFET operation in enhancement mode?
- c) For a fixed bias circuit using NPN transistor, the value of β is 80. If $R_b = 390K\Omega$, $R_c = 1.5K\Omega$ and $V_{cc} = 30V$. find the coordinates of the Q-Point.
- d) Discuss the different Differential amplifier configuration? Which is most commonly used and why?
- e) What is an oscillator? How does it differ from an amplifier? What are the essential parts of an oscillator circuit?

SECTION C**3. Attempt any one part of the following: 10 x 1 = 10**

- a) Why op-amps are used generally in closed loop configuration? Explain?
- b) Determine the voltage gain, input resistance, output resistance and bandwidth of the inverter. The IC op-amp connected in the circuit has the following parameter-
 $A = 2 \times 10^5$, $R_i = 2M\Omega$, $R_o = 75\Omega$, $f_0 = 5Hz$.

4. Attempt any one part of the following: 10 x 1 = 10

- a) Explain Frequency response of a Common Source Amplifier?
- b) Compare between (i) NMOS and PMOS (ii) JFET and MOSFET

5. Attempt any *one* part of the following: 10 x 1=10
- a) Explain EBERS-MOLL Model of a transistor?
 - b) Explain how device capacitance plays dominant role in CE amplifier in high frequency region?
6. Attempt any *one* part of the following: 10 x 1=10
- a) Discuss the circuit diagram of an active load in a differential amplifier?
 - b) Determine the output voltage of an op-amp for the input voltage of $V_1=150\mu\text{V}$, $V_2=140\mu\text{V}$. The amplifier has a differential gain of 4000 and the value of CMRR is (i) 100 and (ii) 10^5
7. Attempt any *one* part of the following: 10 x 1=10
- a) Discuss the effect of negative feedback on voltage gain, stability, distortion, bandwidth, output and input impedance of an amplifier?
 - b) Draw and discuss in detail the circuit of an RC phase shift oscillator?